

# **MDV03-400**

## ULTRA-FAST RECOVERY DIODE

#### MAJOR PRODUCTS CHARACTERISTICS

F(AV)	3 A
V <sub>RRM</sub>	400 V
t <sub>rr</sub>	25 ns
V <sub>F</sub> (max)	1.4 V

#### FEATURES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING

#### DESCRIPTION

Ultra-fast diode especially designed for modulation and flyback rectification in standard and high resolution displays for TV's and monitors. The device is packaged in a DO-201AD axial enveloppe.

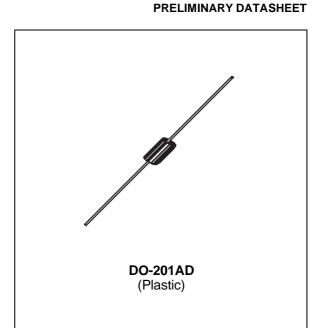
ioppe.								
ABSOLUTE RATINGS (limiting values)								
Symbol	Parameter	Value	Unit					
V <sub>RRM</sub>	Repetitive peak reverse voltage	Repetitive peak reverse voltage 400 V						
V <sub>RSM</sub>	Non repetitive peak reverse voltage	Non repetitive peak reverse voltage 440 V						
I <sub>FRM</sub>	Repetive peak forward current	60	А					
I <sub>F (AV)</sub>	Average forward current*	$T_{a=65}$ °C $\delta = 0.5$	3	A				
IFSM	Surge non repetitive forward current	t <sub>p</sub> = 10ms Sinusoidal	60	A				
Р	Power dissipation *	4.2	W					
T <sub>stg</sub> Tj	Storage and junction temperature range- 40 to + 150°- 40 to + 150- 40 to + 150							

#### THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R <sub>th</sub> (j - l)	Junction to lead	20	°C/W
Rth (j - a)	Junction to ambient on printed circuit L lead = 10mm	75	°C/W

\* On infinite heatsink with 10mm lead lengh.

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#### MDV03-400

#### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions		Тур.	Max.	Unit
I <sub>R</sub> *	Reverse Leakage Current	$V_R = V_{RRM}$	Tj = 25°C Tj = 100°C		20 0.5	μA mA
VF **	Forward Voltage Drop	I <sub>F</sub> = 3 A	Tj = 25℃ Tj = 100℃		1.5 1.4	V V

Pulse test : \*tp=5ms,  $\delta$  < 2% \*\*tp = 380  $\mu s, \, \delta$  < 2%

DYNAMIC ELECTRICAL CHARACTERISTICS

**TURN-OFF SWITCHING** 

Symbol	Parameter	Test Conditions	Тур.	Max.	Unit
trr	Reverse Recovery Time	I <sub>F</sub> =1A di <sub>F</sub> /dt= -15A/µs V <sub>R</sub> = 30V		55	ns
		$I_F = 0.5A$ $I_R = 1A$ $Irr = 0.25A$		25	ns

#### DYNAMIC ELECTRICAL CHARACTERISTICS **TURN-ON SWITCHING**

Symbol	Parameter	Test Conditions	Тур.	Max.	Unit
t <sub>fr</sub>	Forward Recovery Time	$I_F = 3 A$ $dI_F/dt = 60 A/\mu s$		250	ns
V <sub>FP</sub>	Peak Forward Voltage	Measured at 1.1 V <sub>F</sub> max. Tj = 25℃		13	V

To evaluate the maximum conduction losses use the following equation :

$$P = \frac{1.10 \ x \ l_p}{2} x \ \delta + \frac{0.050 \ x \ l_p}{3} \frac{2}{3} x \ \delta$$

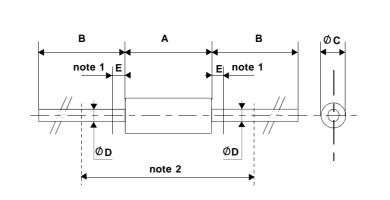
 $\delta$  : duty cycle I\_p : Peak current

Ex : for  $I_p = 3 A$  and  $\delta = 0.5$ , P = 0.9 Watts.



### PACKAGE MECHANICAL DATA

DO-201AD (Plastic)



	DIMENSIONS				
REF.	Millimeters		s Inches		NOTES
	Min.	Max.	Min. Max.		
А		9.50		0.374	1 - The lead diameter $\oslash$ D is not controlled over zone E
В	25.40		1.000		2 - The minimum axial lengh within which the device may be
ØC		5.30		0.209	placed with its leads bent at right angles is 0.59"(15 mm)
ØD		1.30		0.051	
E		1.25		0.049	

Weight : 1 g Marking : Type number - Date code White band indicated cathode cooling methode : by convertion ( method A)

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